



Broadband opto-electrical receivers in standard CMOS /

Hermans, Carolien

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Monografía

"This book fits in the quest for integrated opto-electrical solutions, and focuses on the receiver front-end. To further reduce the cost, the cheapest technology is selected: standard CMOS, without any optical tricks or flavors. The emphasis lies on the analysis design and implementation of high performance analog receiver circuits."--Jacket

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